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#### **ON Semiconductor**<sup>®</sup>



## ASM3P2669A

## Peak EMI Reducing Solution

#### Features

- Generates a 1X low EMI spread spectrum clock of the input frequency.
- Integrated loop filter components.
- Operates with a 3.3V / 2.5V supply.
- Operating current less than 4mA.
- CMOS design.
- Input frequency range: 6MHz to 12MHz for 2.5V
  6MHz to 13MHz for 3.3V
- Frequency deviation: ±1% @ 10MHz
- 6L-TSOP (6L-TSOT-23)

### **Product Description**

**Block Diagram** 

The ASM3P2669A is a versatile spread spectrum frequency modulator designed specifically for a wide range of clock frequencies. The ASM3P2669A reduces electromagnetic interference (EMI) at the clock source, allowing system wide reduction of EMI of all clock dependent signals. The ASM3P2669A allows significant

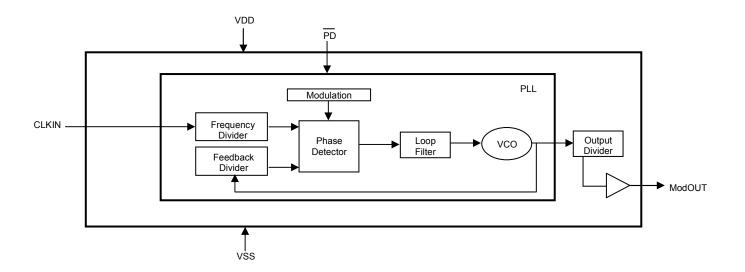
## system cost savings by reducing the number of circuit board layers, ferrite beads and shielding that are traditionally required to pass EMI regulations.

The ASM3P2669A uses the most efficient and optimized modulation profile approved by the FCC and is implemented by using a proprietary all digital method.

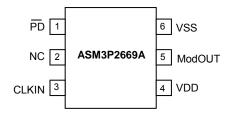
The ASM3P2669A modulates the output of a single PLL in order to "spread" the bandwidth of a synthesized clock, and more importantly, decreases the peak amplitudes of its harmonics. This results in significantly lower system EMI compared to the typical narrow band signal produced by oscillators and most frequency generators. Lowering EMI by increasing a signal's bandwidth is called 'spread spectrum clock generation.'

## Application

The ASM3P2669A is targeted towards all portable devices like MP3 players and digital still cameras.



## Pin Configuration (6L- TSOP Package)



## **Pin Description**

Pin#	Pin Name	Туре	Description
1	PD	Ι	Power-down control pin. Pull low to enable power-down mode. Connect to VDD if not used.
2	NC	-	No connect.
3	CLKIN	I	External reference clock input.
4	VDD	Р	Power supply for the entire chip.
5	ModOUT	0	Spread spectrum clock output.
6	VSS	Р	Ground connection.

## Specifications

VDD (V)	Frequency Range (MHz)	Modulation Rate
2.5	6-12	F <sub>IN</sub> /256
3.3	6-13	FIN/230

### **Absolute Maximum Ratings**

Symbol	Parameter	Rating	Unit	
VDD, V <sub>IN</sub>	Voltage on any pin with respect to Ground	-0.5 to +4.6	V	
T <sub>STG</sub>	Storage temperature	-65 to +125	C	
Ts	Max. Soldering Temperature (10 sec)	260	C	
TJ	Junction Temperature	150	C	
T <sub>DV</sub> Static Discharge Voltage 2 K (As per JEDEC STD22- A114-B)				
Note: These are s device relia	tress ratings only and are not implied for functional use. Exposure to absolute maximum ratings fo pility.	or prolonged periods of time	may affect	

## **Operating Conditions**

Parameter	Description	Min	Max	Unit
VDD	Supply Voltage	2.375	3.6	V
T <sub>A</sub>	Operating Temperature (Ambient Temperature)	-40	+85	C
CL	Load Capacitance		15	pF
CIN	Input Capacitance		7	pF

Symbol	Parameter	Min	Тур	Max	Unit
VIL	Input low voltage	VSS-0.3		0.8	V
V <sub>IH</sub>	Input high voltage	2.0		VDD+0.3	V
IIL	Input low current			-35	μA
I <sub>IH</sub>	Input high current			35	μA
V <sub>OL</sub>	Output low voltage (VDD = 2.5 V, I <sub>OL</sub> = 8mA)			0.6	V
V <sub>OH</sub>	Output high voltage (VDD = 2.5 V, I <sub>OH</sub> = 8mA)	1.8			V
I <sub>DD</sub>	Static supply current <sup>1</sup>			10	uA
Icc	Dynamic supply current (Unloaded Output)		2	2.5	mA
VDD	Operating voltage	2.375	2.5	2.625	V
t <sub>ON</sub>	Power-up time (first locked cycle after power-up) <sup>2</sup>			5	mS
Z <sub>OUT</sub>	Output impedance		40		Ω
	CLKIN pin and PD pin are pulled <u>low</u> . nd XIN / CLKIN input are stable, PD pin is made high from low.				

### DC Electrical Characteristics for 2.5V Supply

## AC Electrical Characteristics for 2.5V Supply

Symbol	Parameter	Min	Тур	Max	Unit	
CLKIN	Input frequency		6		12	MHz
ModOUT	Output frequency		6		12	MHz
		CLKIN = 6MHz		±1.25		%
f <sub>d</sub>	Frequency Deviation	CLKIN = 10MHz		±1		
		CLKIN = 12MHz		±0.9		
t <sub>LH</sub> 1	Output Rise time (measured from	Output Rise time (measured from 0.7V to 1.7V)			2.5	nS
t <sub>HL</sub> 1	Output Fall time (measured from	1.7V to 0.7V)	0.6	1	1.5	nS
t <sub>D</sub>	Output Duty Cycle		45	50	55	%
t <sub>JC</sub>	Cycle-to-Cycle Jitter		±250	±400	pS	
Note: 1. t <sub>LH</sub> and	d $t_{HL}$ are measured into a capacitive load of 1	5pF.				

Symbol	Parameter	Min	Тур	Max	Unit
VIL	Input low voltage	VSS-0.3		0.8	V
V <sub>IH</sub>	Input high voltage	2.0		VDD+0.3	V
IIL	Input low current			-35	μA
I <sub>IH</sub>	Input high current			35	μA
V <sub>OL</sub>	Output low voltage (VDD = 3.3 V, I <sub>OL</sub> = 8mA)			0.4	V
V <sub>OH</sub>	Output high voltage (VDD = 3.3 V, I <sub>OH</sub> = 8mA)	2.5		-	V
I <sub>DD</sub>	Static supply current <sup>1</sup>			10	uA
Icc	Dynamic supply current (Unloaded Output)		2.5	3	mA
VDD	Operating voltage	2.7	3.3	3.6	V
t <sub>on</sub>	Power-up time (first locked cycle after power-up) <sup>2</sup>			5	mS
Z <sub>OUT</sub>	Output impedance		35		Ω
	CLKIN pin and PD pin are pulled <u>lo</u> w. Ind XIN / CLKIN input are stable, PD pin is made high from low.				

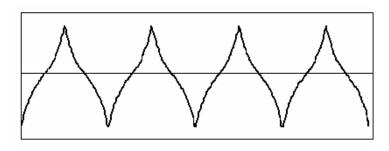
### **DC Electrical Characteristics for 3.3V Supply**

## AC Electrical Characteristics for 3.3V Supply

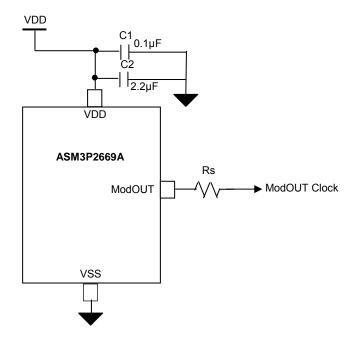
Symbol	F	Min	Тур	Max	Unit	
CLKIN	Input frequency		6		13	MHz
ModOUT	Output frequency		6		13	MHz
		CLKIN = 6MHz		±1.25		
f <sub>d</sub>	Frequency Deviation	CLKIN = 10MHz		±1		%
		CLKIN = 13MHz		±0.9		
t <sub>LH</sub> 1	Output Rise time (measured from 0.8V to 2.0V)		0.7	1.3	1.7	nS
t <sub>HL</sub> 1	Output Fall time (measured at 2.0V to 0.8V)		0.6	0.9	1.3	nS
t <sub>D</sub>	Output Duty Cycle		45	50	55	%
t <sub>JC</sub>	Cycle - Cycle Jitter		±300	±450	pS	
Note: 1. t <sub>LH</sub> and	d t <sub>HL</sub> are measured into a capac	itive load of 15pF.		•	•	

Note: 1.  $t_{LH}$  and  $t_{HL}$  are measured into a capacitive load of 15pF. Note: All parameters are at an Extended Industrial temperature range unless otherwise stated.

## **Modulation Profile**



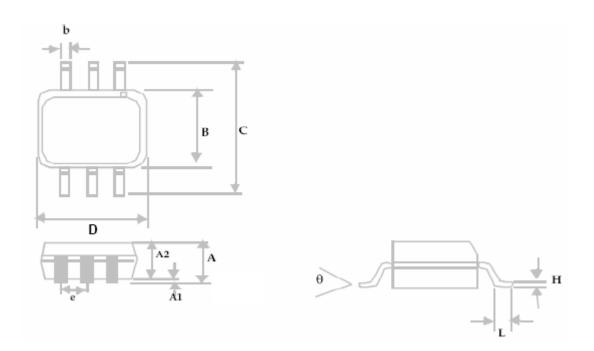
## **Typical Application Schematic**



## ASM3P2669A

## **Package Information**

6L-TSOP Package



	Dimensions				
Symbol	Inc	hes	Millimeters		
	Min	Мах	Min	Max	
А		0.04		1.00	
A1	0.00	0.004	0.00	0.10	
A2	0.033	0.036	0.84	0.90	
b	0.012	0.02	0.30	0.50	
Н	0.005	BSC	0.127	BSC	
D	0.114 BSC		2.90 BSC		
В	0.06 BSC		1.60 BSC		
е	0.0374 BSC		0.950 BSC		
С	0.11 BSC		2.80	BSC	
L	0.0118	0.02	0.30	0.50	
θ	0°	4°	0°	4°	

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## ASM3P2669A

#### **Ordering Information**

Part Number	Marking	Package Type	Temperature
ASM3P2669AF-06OR	H4L	6L-TSOP (6L-TSOT-23), TAPE & REEL, Pb Free	0℃ to +70℃
ASM312669AF-06OR	H5L	6L-TSOP (6L-TSOT-23), TAPE & REEL, Pb Free	-40℃ to +85℃

A "microdot" placed at the end of last row of marking or just below the last row toward the center of package indicates Pb-free.

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